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Product Termination Notification

Product Group: SIL/Wednesday June 3, 2026/PTN-SIL-008-2026-REV-0



Conversion to Copper (Cu) Wire – SQ2315ES-T1_BE3

For further information, please contact your regional Vishay office.

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Description of Change: The affected part number listed in this notification will be converted to a Copper wire material set. The new ordering code is SQ2315CES-T1_BE3 which has Identical silicon technology and silicon die design as SQ2315ES. Small changes to the data sheet AC parameters are a consequence of lot to lot variation and/or updated characterization methods (reference: SQ2315CES Doc # 62255 Rev. A). Device performance in the application will not be impacted. There will be no change to the wafer fab location.

Reason for Change: Standardization of materials

Expected Influence on Quality/Reliability/Performance: None

Part Numbers/Series/Families Affected: SQ2315ES-T1_BE3

Vishay Brand(S): Vishay Siliconix

Time Schedule:

Last Time Buy Date: Wednesday December 23, 2026

Last Time Ship Date: Wednesday June 23, 2027

Sample Availability: Qualified samples of replacement product are available on request.

Product Identification: SQ2315CES-T1_BE3

Qualification Data: AEC Q101 qualification data of replacement product is available. Qualification PPAP is available on request.

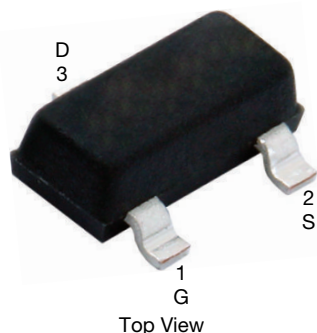
This PTN is considered approved, without further notification, unless we receive specific customer concerns before Monday December 14, 2026 or as specified by contract.

Issued By: Lance Gurrola, automostechsupport.com



Automotive P-Channel 12 V (D-S) 175 °C MOSFET

SOT-23 (TO-236)



Top View

Marking Code: 9T

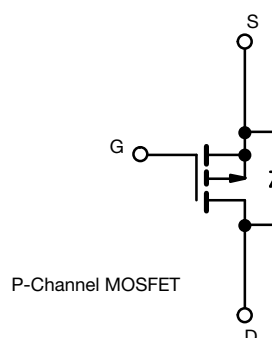
PRODUCT SUMMARY	
V_{DS} (V)	-12
$R_{DS(on)}$ (Ω) at $V_{GS} = -4.5$ V	0.050
$R_{DS(on)}$ (Ω) at $V_{GS} = -2.5$ V	0.068
$R_{DS(on)}$ (Ω) at $V_{GS} = -1.8$ V	0.100
I_D (A)	-5
Configuration	Single

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE



ORDERING INFORMATION

Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2315CES (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V_{DS}	-12	V
Gate-source voltage	V_{GS}	± 8	V
Continuous drain current	I_D	$T_C = 25$ °C	-5
		$T_C = 125$ °C	-3
Continuous source current (diode conduction)	I_S	-2.5	A
Pulsed drain current ^a	I_{DM}	-20	A
Single pulse avalanche current	I_{AS}	-11	A
Single pulse avalanche energy	E_{AS}	6	mJ
Maximum power dissipation	P_D	$T_C = 25$ °C	2
		$T_C = 125$ °C	0.67
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient	R_{thJA}	175	°C/W
Junction-to-foot (drain)	R_{thJF}	75	°C/W

Notes

- a. Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %
b. When mounted on 1" square PCB (FR4 material)



SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA		-12	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA		-0.45	-	-1	
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 8 V		-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -12 V	-	-	-1	μA
		V _{GS} = 0 V	V _{DS} = -12 V, T _J = 125 °C	-	-	-50	
		V _{GS} = 0 V	V _{DS} = -12 V, T _J = 175 °C	-	-	-150	
On-state drain current ^a	I _{D(on)}	V _{GS} = -4.5 V	V _{DS} ≤ -5 V	-10	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5 V	I _D = -3.5 A	-	0.042	0.050	Ω
		V _{GS} = -4.5 V	I _D = -3.5 A, T _J = 125 °C	-	-	0.066	
		V _{GS} = -4.5 V	I _D = -3.5 A, T _J = 175 °C	-	-	0.075	
		V _{GS} = -2.5 V	I _D = -3 A	-	0.059	0.068	
		V _{GS} = -1.8 V	I _D = -2 A	-	0.084	0.100	
Forward transconductance ^b	g _{fs}	V _{DS} = -5 V, I _D = -1.6 A		-	7	-	S
Dynamic ^b							
Input capacitance	C _{iss}	V _{GS} = 0 V	V _{DS} = -6 V, f = 1 MHz	-	704	870	pF
Output capacitance	C _{oss}			-	276	335	
Reverse transfer capacitance	C _{rss}			-	215	240	
Total gate charge ^c	Q _g	V _{GS} = -4.5 V	V _{DS} = -6 V, I _D = -3.85 A	-	9.3	13	nC
Gate-source charge ^c	Q _{gs}			-	1.4	-	
Gate-drain charge ^c	Q _{gd}			-	3.0	-	
Gate resistance	R _g	f = 1 MHz		2.4	4.9	12.3	Ω
Turn-on delay time ^c	t _{d(on)}	V _{DD} = -6 V, R _L = 1.6 Ω I _D ≅ -3.85 A, V _{GEN} = -4.5 V, R _g = 1 Ω		-	11	26	ns
Rise time ^c	t _r			-	27	30	
Turn-off delay time ^c	t _{d(off)}			-	24	42	
Fall time ^c	t _f			-	14	20	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed current ^a	I _{SM}			-	-	-20	A
Forward voltage	V _{SD}	I _F = -2 A, V _{GS} = 0 V		-	-0.8	-1.2	V
Body diode reverse recovery time	t _{rr}	I _F = -1.2 A, di/dit = 100 A/μs		-	22	44	ns
Body diode reverse recovery charge	Q _{rr}			-	9	18	nC
Reverse recovery fall time	t _a			-	10	-	ns
Reverse recovery rise time	t _b			-	12	-	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-0.674	-	A

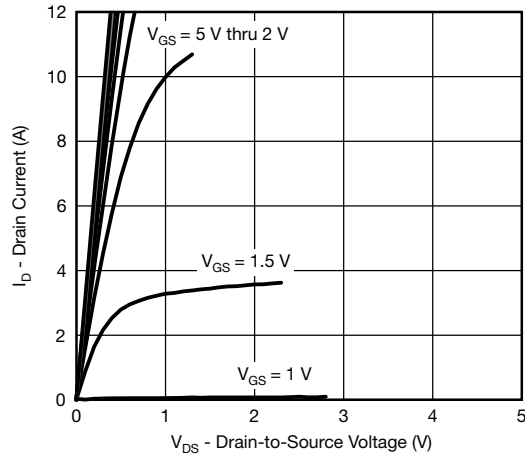
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing
c. Independent of operating temperature

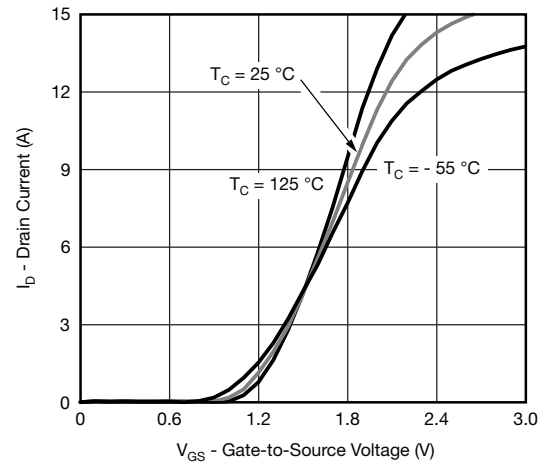
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



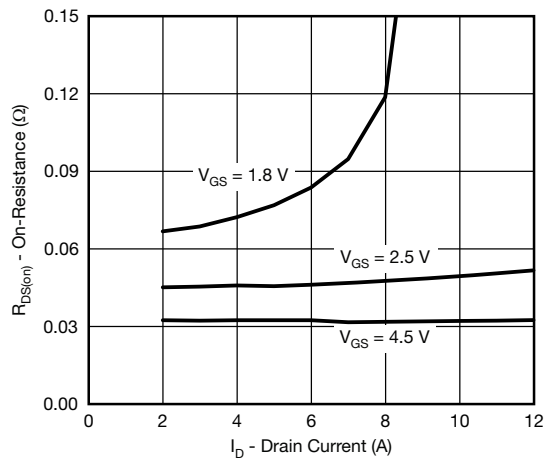
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



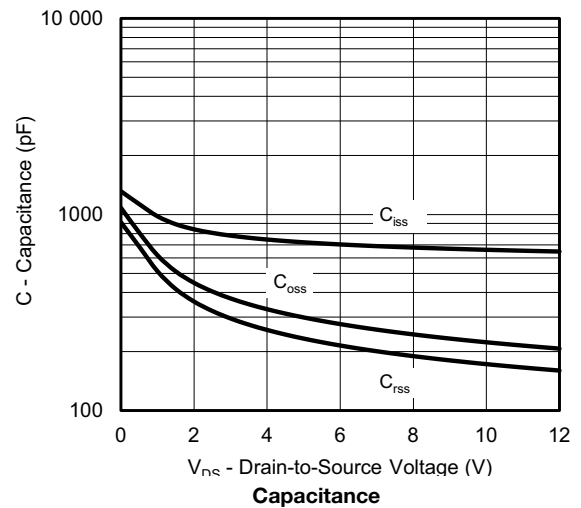
Output Characteristics



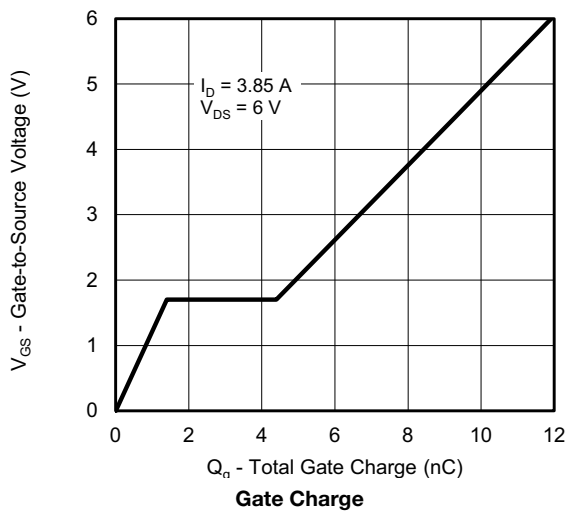
Transfer Characteristics



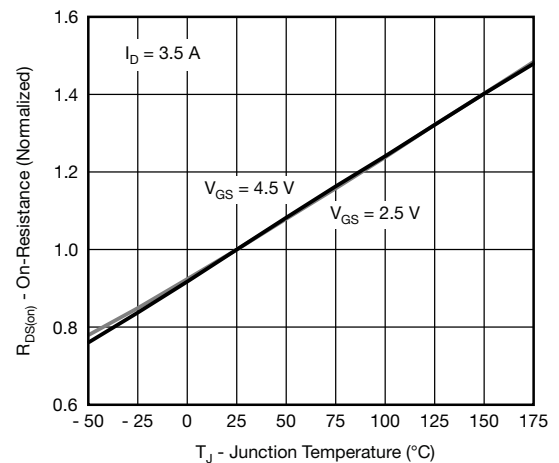
On-Resistance vs. Drain Current



Capacitance



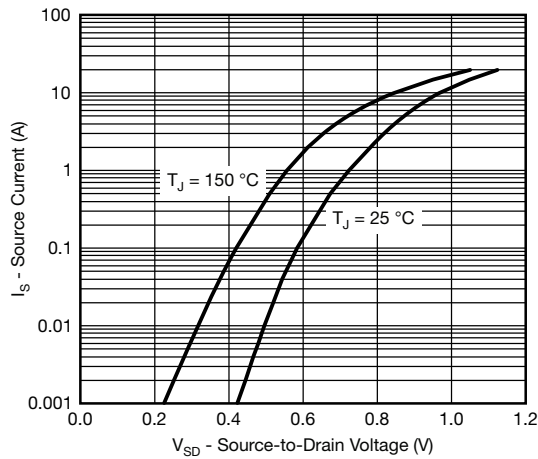
Gate Charge



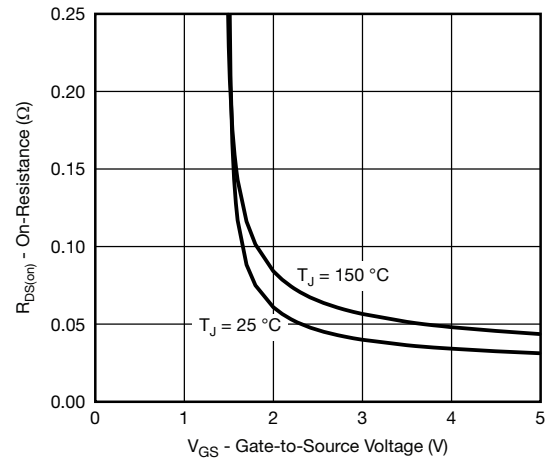
On-Resistance vs. Junction Temperature



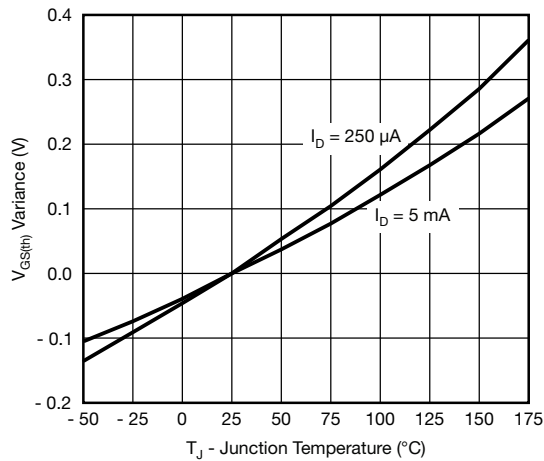
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



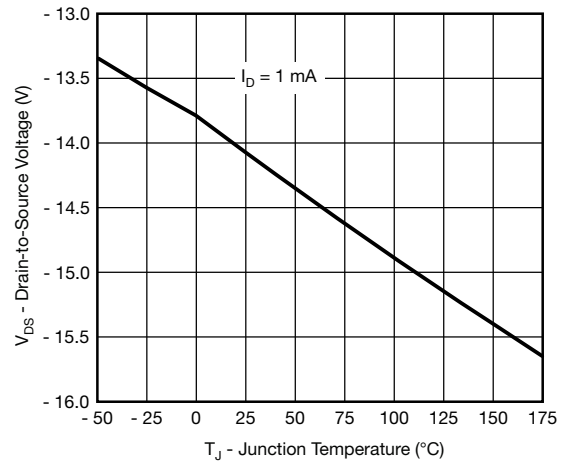
Source-Drain Diode Forward Voltage



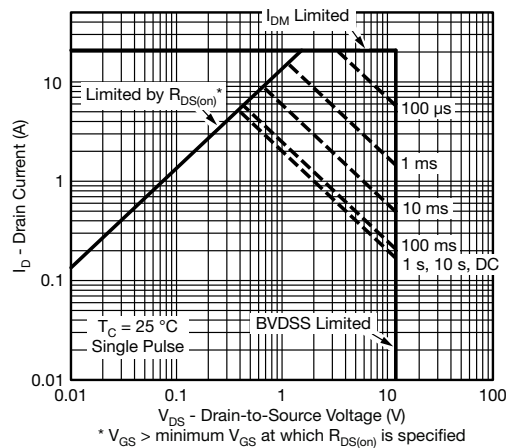
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



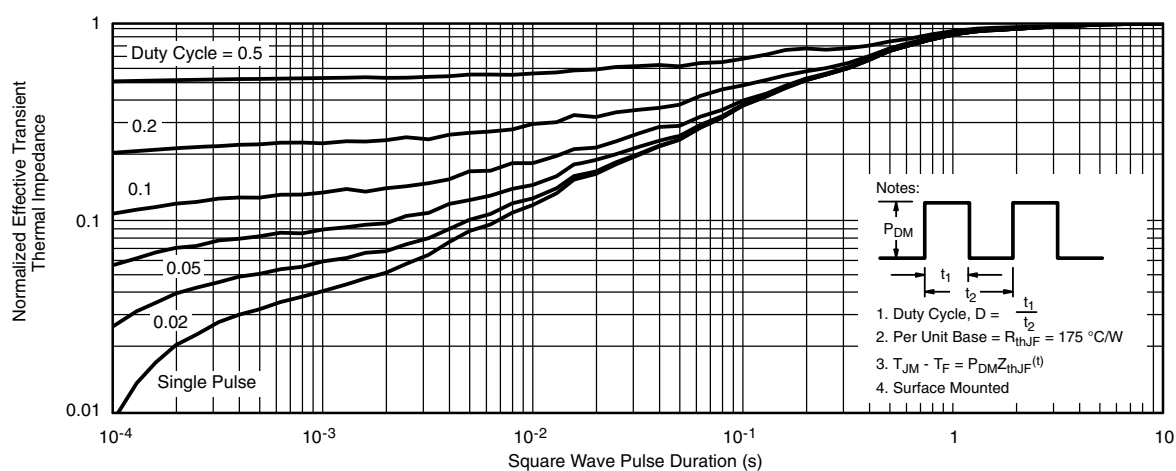
Drain Source Breakdown vs. Junction Temperature



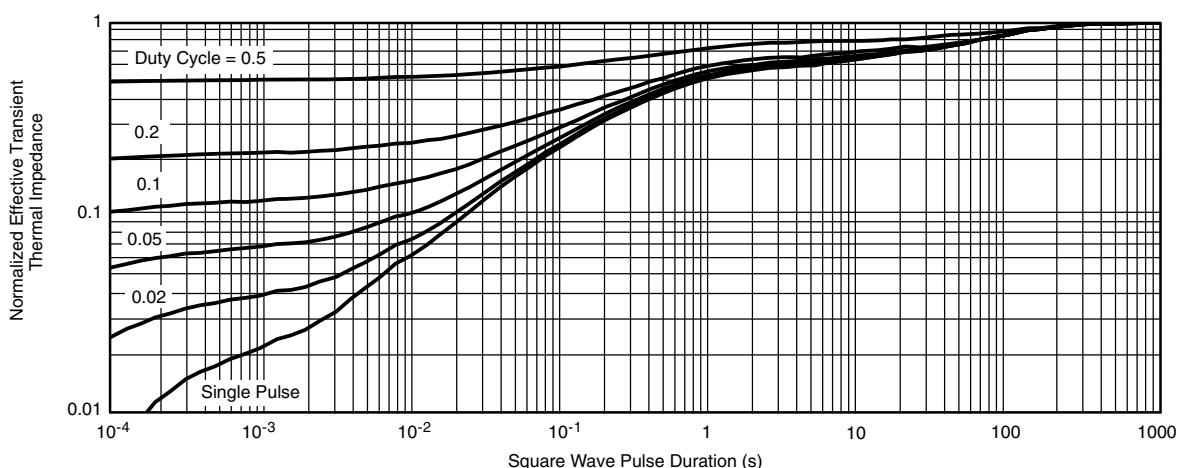
Safe Operating Area



THERMAL RATINGS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot



Normalized Thermal Transient Impedance, Junction-to-Ambient

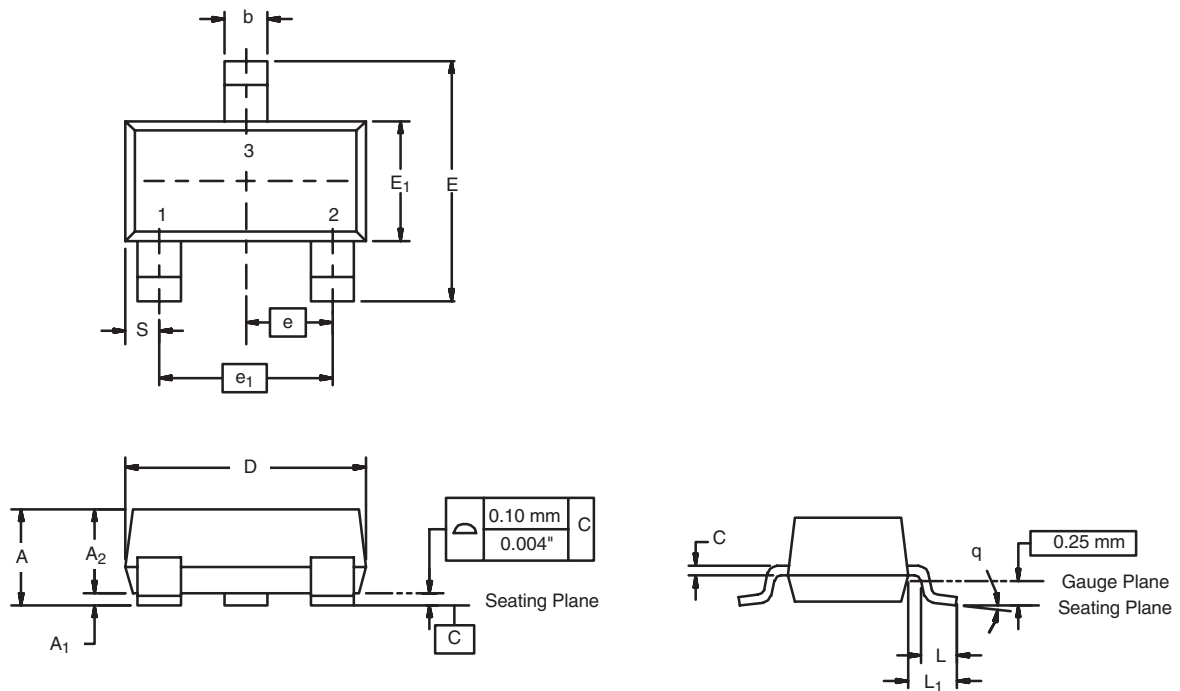
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^{\circ}\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Case ($25\text{ }^{\circ}\text{C}$)
- are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62255.



SOT-23 (TO-236): 3-LEAD

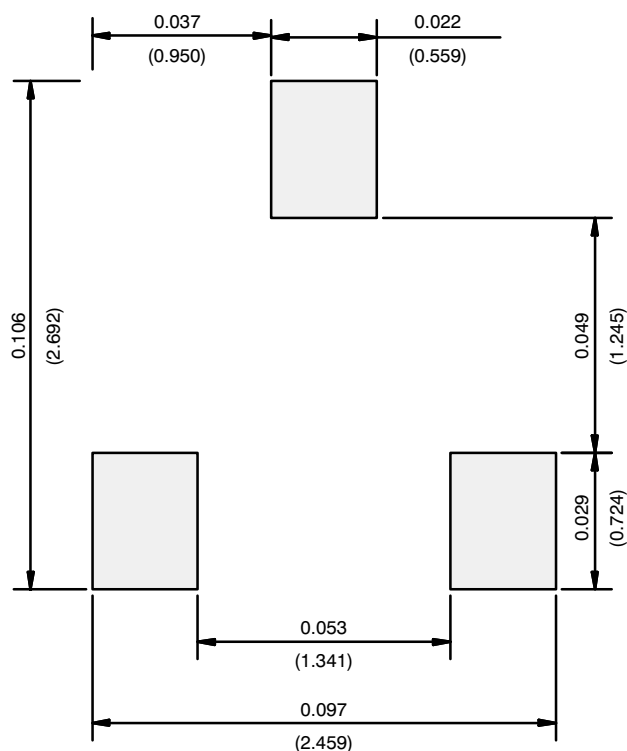


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A ₁	0.01	0.10	0.0004	0.004
A ₂	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E ₁	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e ₁	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L ₁	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

ECN: S-03946-Rev. K, 09-Jul-01
DWG: 5479



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

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Vishay Material Code	Customer Material	Location
SQ2315ES-T1_BE3	SLNSQ2315ES-T1-BE3	Ft Worth